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Typical Applications

The HMC442LC3B is an ideal gain block or driver amplifier for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- LO Driver for HMC Mixers
- Military EW & ECM

Functional Diagram



HMC442LC3B

GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 17.5 - 25.5 GHz

Features

Gain: 13 dB Saturated Power: +23 dBm @ 26% PAE Supply Voltage: +5V 50 Ohm Matched Input/Output RoHS Compliant 3 x 3 mm SMT package

General Description

The HMC442LC3B is an efficient GaAs PHEMT MMIC Medium Power Amplifier housed in a leadless "Pb free" RoHS compliant SMT package. Operating between 17.5 and 25.5 GHz, the amplifier provides 13 dB of gain, +23 dBm of saturated power and 26% PAE from a +5V supply voltage. This 50 Ohm matched amplifier does not require any external components, making it an ideal linear gain block or driver for HMC SMT mixers. The HMC442LC3B allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vdd = +5V, Idd = 84 mA*

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	17.5 - 21.0		21.0 - 24.0		24.0 - 25.5		GHz			
Gain	10	13		10	13		8	11		dB
Gain Variation Over Temperature		0.02	0.03		0.02	0.03		0.02	0.03	dB/ °C
Input Return Loss		10			10			5		dB
Output Return Loss		9			9			12		dB
Output Power for 1 dB Compression (P1dB)	18	21		19	22		19	22		dBm
Saturated Output Power (Psat)		23			23.5			23		dBm
Output Third Order Intercept (IP3)		27			26			26		dBm
Noise Figure		8			8			9		dB
Supply Current (Idd)(Vdd = 5V, Vgg = -1V Typ.)		84			84			84		mA

*Adjust Vgg between -1.5 to -0.5V to achieve Idd = 84 mA typical.

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GaAs PHEMT MMIC MEDIUM

POWER AMPLIFIER, 17.5 - 25.5 GHz

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Broadband Gain & Return Loss



Input Return Loss vs. Temperature



P1dB vs. Temperature





Output Return Loss vs. Temperature



Psat vs. Temperature



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Power Compression @ 18 GHz



Output IP3 vs. Temperature



Gain, Power and Output IP3 vs. Supply Voltage @ 23 GHz



GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 17.5 - 25.5 GHz



Noise Figure vs. Temperature



Reverse Isolation vs. Temperature



(mgp) Paat (dBm), Paat (dBm) and Single Support of the sector of the sec

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GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 17.5 - 25.5 GHz

Absolute Maximum Ratings

+5.5 Vdc
-8.0 to 0 Vdc
+16 dBm
175 °C
0.491 W
183 °C/W
-65 to +150 °C
-40 to +85 °C
Class 1A

Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)
+4.5	82
+5.0	84
+5.5	86

Note: Amplifier will operate over full voltage range shown above



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS







NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA

- 2. LEAD AND GROUND PADDLE PLATING: 30 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].

4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE

- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

[Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]	
	HMC442LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H442 XXXX	

[1] Max peak reflow temperature of 260 $^\circ\text{C}$

[2] 4-Digit lot number XXXX

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GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 17.5 - 25.5 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic		
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground			
2	RFIN	This pin is AC coupled and matched to 50 Ohms.			
4, 6, 10, 12	N/C	This pin may be connected to RF/DC ground. Performance will not be affected.			
5	Vgg	Gate control for amplifier. Adjust to achieve Id of 84 mA. Please follow "MMIC Amplifier Biasing Procedure" Application Note.	Vgg o		
8	RFOUT	This pin is AC coupled and matched to 50 Ohms.			
11	Vdd	Power Supply Voltage for the amplifier. External bypass capacitors are required.	⊖Vdd ⊢ —		

Application Circuit

Component	Value		
C1, C2	100 pF		
C3, C4	1,000 pF		
C5, C6	2.2 µF		



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Evaluation PCB



List of Materials for Evaluation PCB 109712 [1]

Item	Description	
J1 - J2	PCB Mount SMA Connector	
J3 - J6	DC Pin	
C1 - C2	100 pF Capacitor, 0402 Pkg.	
C3 - C4	1000 pF Capacitor, 0603 Pkg.	
C5 - C6	2.2 µF Capacitor, Tantalum	
U1	HMC442LC3B Amplifier	
PCB ^[2]	109710 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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